

Supplementary Information

Evaluation of ultrananocrystalline diamond size by UV Raman spectroscopy and phonon confinement model

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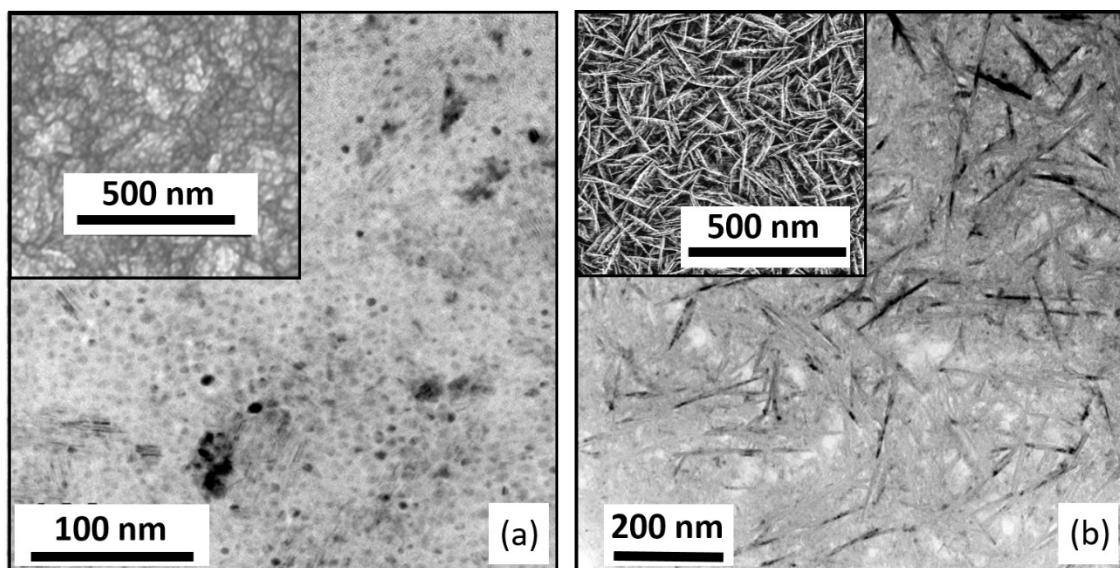


Fig. S1 | SEM and TEM image of (a) ultrananocrystalline diamond and (b) diamond nanowire films showing distinct morphology and microstructures.